





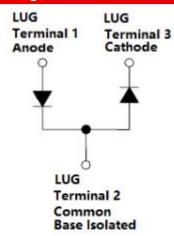
## 603DNQ100C2 SCHOTTKY RECTIFIER



#### **Features**

- 175 ℃ T<sub>J</sub> operation
- High purity, high temperature epoxy encapsulation for
- enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



## **Applications**

- · High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

#### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=122°C, In DC	300(Per Leg) 600(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	6000	А

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@300A, Pulse, T <sub>J</sub> = 25°C	-	0.88	V
	V <sub>F2</sub>	@300A, Pulse, T <sub>J</sub> = 175°C	-	0.68	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = rated V_R$ , $T_J = 25^{\circ}C$	-	8	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ , $T_J = 125^{\circ}C$	-	75	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	-	9000	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

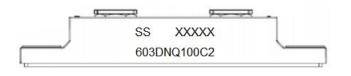
Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +175		°C
Storage Temperature	$T_{stg}$	-	-55 to +175		°C
Typical Thermal Resistance Junction to Case(Per leg)	$R_{ heta JC}$	DC operation	0.20		°C/W
Typical Thermal Resistance Junction to Case(Per package)	$R_{ heta JC}$	DC operation	0.10		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.08		°C/W
Mounting Torque	Mt		To terminals(M6)	4(min) 5.8(max)	- Nm
Mounting Torque	Ms	_	To heatsink(M6)	4(min) 6(max)	INIII
Approximate Weight	wt	-	85		g
Case Style	TO-244(plastic shell)				







## **Marking Diagram**



# **Ordering Information**

Device	Package	Shipping
603DNQ100C2	TO-244(plastic shell)	15 pcs/box

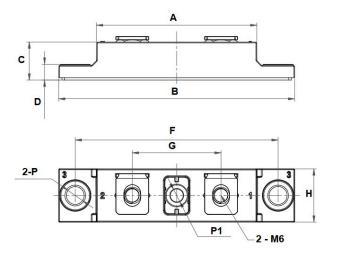
Where XXXXX is YYWWL

603DNQ100C2 = Part name SS = SS YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

## Mechanical Dimensions TO-244(plastic shell)(Millimeters)





SYMBOL	Millimeters		
	Min.	Max.	
Α	63	64	
В	93	94	
С	15	15.5	
D	6.6	7.0	
E	-	17	
F	79.5	80.5	
G	34.5	35.5	
Н	20.5	21.5	
ØP	6.8	7.4	
ØP1	4.9	5.5	

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